DISCRETE SEMICONDUCTORS

DATA SHEET



BAT86Schottky barrier diode

Product specification Supersedes data of April 1992 1996 Mar 20





Schottky barrier diode

BAT86

FEATURES

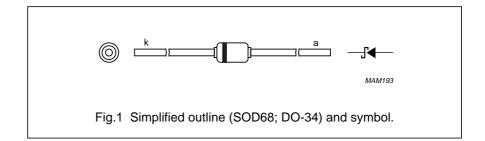
- · Low forward voltage
- · Guard ring protected
- Hermetically-sealed leaded glass package.

APPLICATIONS

- Ultra high-speed switching
- Voltage clamping
- Protection circuits
- · Blocking diodes.

DESCRIPTION

Planar Schottky barrier diode with an integrated protection ring against static discharges, encapsulated in a hermetically-sealed subminiature SOD68 (DO-34) package. The diode is suitable for mounting on a 2 E (5.08 mm) pitch.



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V _R	continuous reverse voltage		_	50	V
I _F	continuous forward current		_	200	mA
I _{F(AV)}	average forward current	PCB mounting, lead length = 4 mm; V_{RWM} = 25 V; a = 1.57; δ = 0.5; T_{amb} = 50 °C; see Fig.2	_	200	mA
I _{FRM}	repetitive peak forward current	$t_p \le 1 \text{ s}; \ \delta \le 0.5$	_	500	mA
I _{FSM}	non-repetitive peak forward current	$t_p \le 10 \text{ ms}$	_	5	А
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		_	125	°C
T _{amb}	operating ambient temperature		-65	+125	°C

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ELECTRICAL CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
V _F	forward voltage	see Fig.3		
		I _F = 0.1 mA	300	mV
		I _F = 1 mA	380	mV
		I _F = 10 mA	450	mV
		I _F = 30 mA	600	mV
		I _F = 100 mA	900	mV
I _R	reverse current	V _R = 40V; see Fig.4; note 1	5	μΑ
t _{rr}	reverse recovery time	when switched from I_F = 10 mA to I_R = 10 mA; R_L = 100 Ω ; measured at I_R = 1 mA; see Fig.6	4	ns
C _d	diode capacitance	f = 1 MHz; V _R = 1 V; see Fig.5	8	pF

Note

1. Pulsed test: t_p = 300 μ s; δ = 0.02.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th j-a}	thermal resistance from junction to ambient	note 1	320	K/W

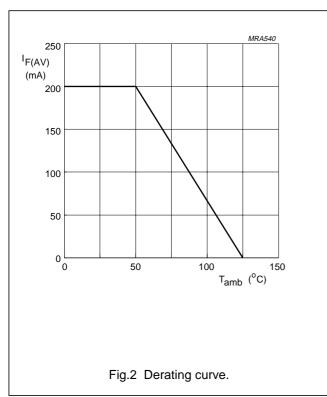
Note

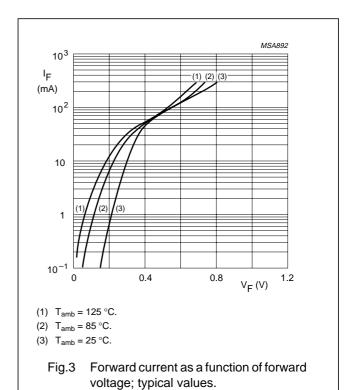
1. Refer to SOD68 standard mounting conditions.

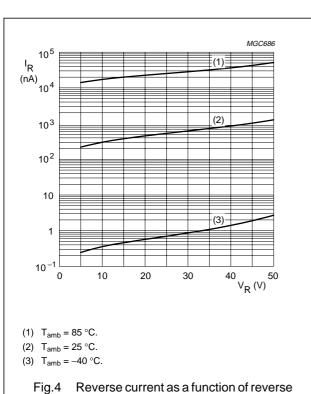
Schottky barrier diode

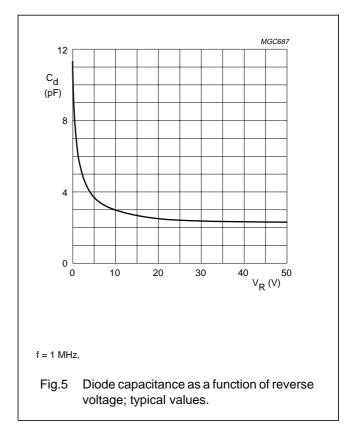
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GRAPHICAL DATA









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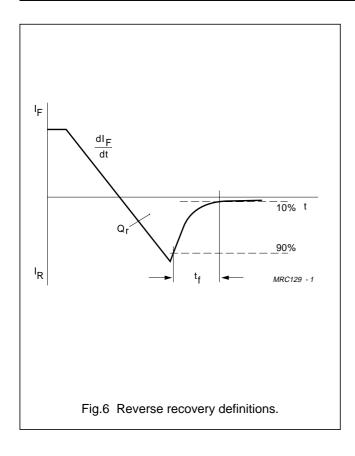
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voltage; typical values.

Fig.4

Schottky barrier diode

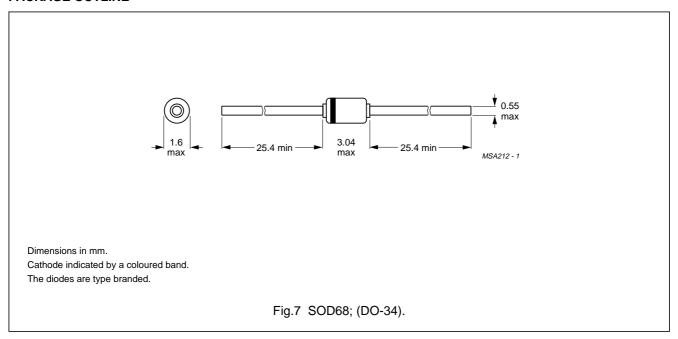
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PACKAGE OUTLINE



DEFINITIONS

Data sheet status			
Objective specification	This data sheet contains target or goal specifications for product development.		
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.		
Product specification	This data sheet contains final product specifications.		
Limiting values			
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification			

Application information

Where application information is given, it is advisory and does not form part of the specification.

is not implied. Exposure to limiting values for extended periods may affect device reliability.

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.